Optical Frequency/Time Measurement and Generation

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Monday, 23 July 2007
MC1  Atomic Frequency Standards I
MC1.1 Atomic Frequency Standards and Their Impact on the Past, Present and Future of the Second... 143
MC1.2 Present Status of the Development of the Yb Optical Lattice Clock at NMIJ/AIST... 145
MC1.3 Direct Two-Photon Resonant Excitation and Absolute Frequency Measurement of Cesium Transitions using a Femtosecond Comb... 147

MC2  Atomic Frequency Standards II
MC2.1 The Yb and Ca Standards: Approaches to High Stability, High Accuracy, and Transportable Optical Atomic Clocks... 149
MC2.2 Measurement of Acetylene-d Absorption Lines with a Self-Referenced Fiber Laser Frequency Comb... 151
MC2.3 Frequency Measurement of an Optical Lattice Clock... 153

MC3  Femtosecond Sources and Combs
MC3.1 Super-Stable Optical Comb and Pulse Generation using Electro-Optic Modulation... 155
MC3.2 Widely Tunable (1.0-1.7 µm) Yb-doped Fiber Mode-Locked Laser Source with ~100 fs Pulse Widths based on Raman Frequency Shift... 157
MC3.3 Quantitative Measurement of the Dynamics of a Mode-Locked Laser... 159
MC3.4 Er- and Yb-doped Fiber Laser Frequency Combs and Their Applications... 161

MC4  Advanced Laser Sources
MC4.1 Frequency Comb Generation in a Monolithic Ring Resonator...N/A
MC4.2 High Power (>150 mW) Electrically Pumped Semiconductor Modelocked Lasers at 1550 nm with Pulse Widths Approaching 6 ps... 163
MC4.3 Narrow Linewidth 1.5 µm Sources and the Thermal Limit... 165
MC4.4 Slab-Coupled Optical Waveguide Devices for Low-Noise Signal Generation... 167

Tuesday, 24 July 2007
TuC1  Optical Arbitrary Waveforms I
TuC1.1 Optical Waveform Generation, Measurement and Utilization... 169
TuC1.2 Optical Arbitrary Pulse Train Generation via Spectral Line-by-Line Pulse Shaping... 170
TuC1.3 Generation of High Repetition Rate Femtosecond Pulse Trains with a High Finesse External Fabry-Perot Cavity... 172

TuC2  Optical Arbitrary Waveforms II
TuC2.1 High Speed Arbitrary Waveform Generation and Processing using a Photonic Digital-to-Analog Converter... 174
TuC2.2 5-GHz Optical Arbitrary Waveform Generation using > 100 Independently Controlled Spectral Lines from a Compressed Phase-Modulated CW Laser Comb... 176
TuC2.3 Increasing the Mode-Spacing of Stabilized Frequency Combs with Optical Filter Cavities... 178
TuC2.4 Ultrafast Time Scale Transformation and Recording Utilizing Parametric Temporal Imaging... 180
TuC3 Frequency Transfer and Metrology
TuC3.1 Precise Long-Distance Frequency Transfer and Applications...N/A
TuC3.2 Large-Scale, Long-Term Stable Femtosecond Timing Distribution and Synchronization Systems... 182
TuC3.3 Optical Frequency Transfer over 38 km of Installed Fiber at Less than 3x10-19 Residual Fractional Instability... 184
TuC3.4 Ultrahigh Dynamic-Range Distance Measurement using a Femtosecond Frequency Comb... 186
TuC4 Millimeter wave and Terahertz Signal Generation
TuC4.1 Techniques for Photonic Generation of Millimeter-Wave Signals... 188
TuC4.2 The Potential of High Speed UTC-TW Photo Detectors to Generate Sub-MM Wave Signals - Predictions by a New Analytical Model... 190
TuC4.3 Microwave Photonic Frequency Multiplication for a Tunable Millimeter and Terahertz CW Signal Generator with Improved Spurious Characteristics... 192
TuC4.4 Microwave Frequency Generation up to 27.5 GHz using a Dual-Wavelength Brillouin Fiber Laser... 194
Abstract – We review the use of slab-coupled optical waveguide amplifiers (SCOWAs) in low-noise mode-locked and single-frequency lasers. We also report a new single-frequency laser cavity incorporating an Er/Yb-codoped waveguide distributed-Bragg-reflector that produces 330-mW power with 75-kHz linewidth.

Introduction
Over the past decade, dramatic improvements in precision metrology and low-noise signal generation have been realized through the development of mode-locked-laser-based optical frequency combs and single-frequency CW lasers. Ultimately, the noise characteristics of both mode-locked and CW lasers are limited by the quality factor (Q) of the laser cavity and the amount of intracavity optical power. However, this quantum-limited performance is often not obtained due to the presence of other noise sources (e.g., cavity length fluctuations, power-supply noise, 1/f noise).

To date, fiber and solid-state lasers have exhibited superior noise performance relative to semiconductor lasers due to their larger intracavity powers, smaller intracavity losses, and negligible gain/index coupling. The main limitation of fiber and solid-state lasers is that their power conversion efficiency is low (typically < 10%) due to optical pumping inefficiencies. Directly-pumped semiconductor lasers offer the potential of higher power efficiency provided that they can be designed to have sufficient noise performance.

We have recently developed a new class of high-power semiconductor optical gain media referred to as the slab-coupled optical waveguide amplifier (SCOWA) [1]. The SCOWA has several attributes that are beneficial for realizing low-noise optical sources: (i) large (5 x 7 µm) fundamental optical mode due to low index-contrast and mode filtering, (ii) large saturation output power (~ 1 W) due to low optical confinement factor (Γ), and (iii) small excess optical loss due to low overlap between the mode and the high-loss p-doped cladding layers. SCOWA applications that have been demonstrated at 1.5-µm include Watt-class power amplifiers, actively mode-locked external-cavity lasers (ECLs) with record-low timing jitter, monolithic passively mode-locked lasers with > 200-mW power, and single-frequency fiber Bragg-grating (FBG) SCOWA-based ECLs (SCOWECLs) producing 90-mW power with ~150-kHz linewidth [2].

In this talk we will review the operating principles of the SCOWA technology and its use in low-noise mode-locked and single-frequency lasers. We report improved FBG SCOWECL performance. We also demonstrate a novel ECL having an external cavity comprising an Er/Yb codoped waveguide distributed Bragg-reflector (DBR).

Single-Frequency External-Cavity Lasers
A primary issue in realizing single-frequency semiconductor ECLs is designing the cavity to maintain stable, single-longitudinal-mode operation with high side-mode suppression. To achieve single-frequency operation, a frequency-selective element must be included in the cavity to reduce the optical bandwidth, thereby allowing only a single mode to oscillate. The narrow bandwidth required becomes increasingly difficult to attain as the length of the active gain medium increases.

We examine two external cavities that enable stable single-mode operation with a long (10 mm) SCOWA gain section. First, we use a long FBG that contains only a few longitudinal modes within its bandwidth. And second, we use a Er/Yb-codoped waveguide containing a relatively short DBR. This doped-cavity approach has previously been used to stabilize semiconductor ECLs comprising meter-length doped-fiber external cavities [3]-[4].

Figure 1 depicts the two SCOWECL cavities that were investigated. Both cavities utilize the same curved-channel InGaAsP quantum-well SCOWA (10-mm length, 100-mm radius) having a high-reflectivity (R > 95%) rear facet and a 5°-angled, anti-reflection (AR) coated front facet [5]. The AR-coated SCOWA facet is directly butt coupled to either an angle-cleaved FBG (Fig. 1(a)) or an angle-polished Er-DBR.
waveguide (Fig. 1(b)).

FBG SCOWECLs were evaluated at three different wavelengths spanning the SCOWA gain bandwidth using FBGs fabricated in HI1060 Flex fiber and having center wavelengths of 1480, 1520, and 1556 nm. The bandwidth and reflectivity of the FBGs were 50 pm (6.2 GHz) and 50%, respectively. The FBGs were angle cleaved at 11° and AR-coated. The distance between the angled fiber facet and the beginning of the FBG was < 2 mm. The mode-diameter of the HI1060 Flex fiber (6.5 µm) is well matched to the large mode profile of the SCOWA (6 x 7.5 µm), enabling butt-coupling efficiency > 60%.

For the three FBG wavelengths evaluated, the best performance was obtained at 1520 nm, which is on the short-wavelength (“blue”) side of the gain spectrum peak at the threshold current of 700 mA. Single-mode operation was verified using a scanning Fabry-Perot interferometer. At I = 2.9 A, the output power was 200 mW and the FWHM linewidth was 40 kHz. Self-heterodyne linewidth measurements (Fig. 2) revealed a Lorentzian lineshape, indicating that white noise was dominant. The threshold currents for both the 1480- and 1556-nm FBGs increased to about 1 A due to the lower gain at these wavelengths. The single-longitudinal-mode stability was notably worse at 1556 nm. We attribute this mode instability to operation on the long-wavelength (“red”) side of the gain spectrum where the linewidth enhancement factor (α) is larger.

The Er/Yb-codoped DBR phosphate-glass waveguide used here was previously used to realize optically pumped 1.5-µm single-frequency lasers producing 80-mW power and 500-kHz linewidth [6]. In our work, the waveguide facets were polished at a 10° angle to reduce the facet reflectivity and allow efficient butt-coupling. The facets were not AR coated. The dimensions shown in Fig. 1(b) are L1 = 1 mm, L2 = 6 mm, and L3 = 10 mm. For this grating length, the DBR bandwidth is approximately 270 pm (33 GHz) and contains many longitudinal modes. The etched DBR center wavelength is 1539 nm and the estimated reflectivity is 65%.

The threshold current for the Er-DBR SCOWECL was 750 mA, which is nearly equal to that of the 1520-nm FBG SCOWECL. Self-heterodyne linewidth measurements (Fig. 3) revealed a Voigt lineshape with Gaussian (Lorentzian) linewidths increasing from 56 to 75 kHz (5.0 to 7.2 kHz) as the current was increased from 1.2 to 3.0 A. The output power at I = 3 A was 330 mW. To our knowledge, this combination of high output power and narrow linewidth is the best that has been achieved for semiconductor ECLs.

Conclusions

We have demonstrated two semiconductor ECL geometries containing a high-power SCOWA gain medium that provide stable single-longitudinal-mode operation. The Er-DBR cavity has higher output power than the FBG cavity (330 vs. 200 mW at ~3 A bias). The lineshapes of the two cavities are considerably different. At I ~ 3A, the total FWHM linewidth of the Er-DBR cavity is almost twice as large as that of the FBG cavity (75 vs. 40 kHz). However, the Er-DBR Voigt

References